

## Peak Emission Wavelength: 950nm

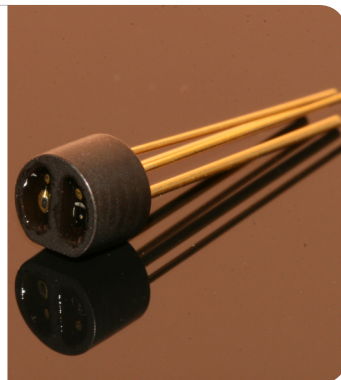
The 950nm reflective sensor consists of a 950nm infrared emitter and high sensitivity photo diode in the same package. The black molded housing reduces the effect of external ambient light. Custom emitter/detectors are available.

### FEATURES

- > High Reliability
- > Compact (Φ4.0)
- > Short Detection Distance Optimum 0.5-1.5mm

### APPLICATIONS

- > Card Reader
- > Bar-code Reader
- > Edge Sensing / Money-bill Reader



## Absolute Maximum Ratings (Ta=25°C)



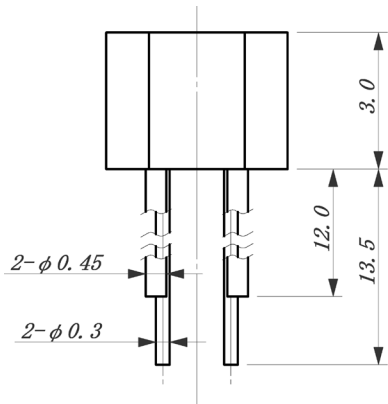
| ITEMS                         | SYMBOL | RATINGS    | UNIT |
|-------------------------------|--------|------------|------|
| Forward Current (LED)         | IF     | 60         | mA   |
| Pulse Forward Current (LED)*1 | IFP    | 1          | A    |
| Reverse Voltage (LED)         | VR     | 5          | V    |
| Power Dissipation (LED)       | PD     | 100        | mW   |
| Reverse Voltage (PD)          | VR     | 30         | V    |
| Power Dissipation (PD)        | PD     | 100        | mW   |
| Total Power Dissipation       | Ptot   | 100        | mW   |
| Operating Temperature Range   | Topr   | -20 ~ +80  | °C   |
| Storage Temperature Range     | Tstg   | -30 ~ +100 | °C   |

\*1: Tw=10μsec, T=10msec.

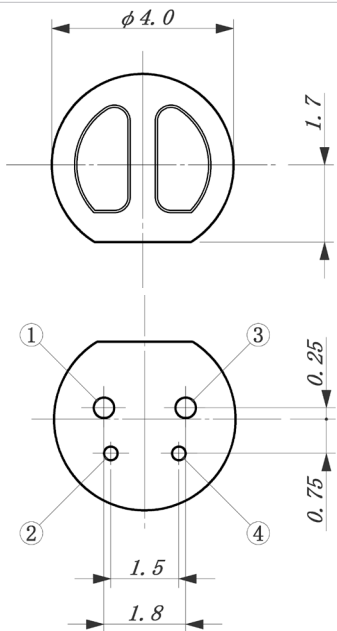
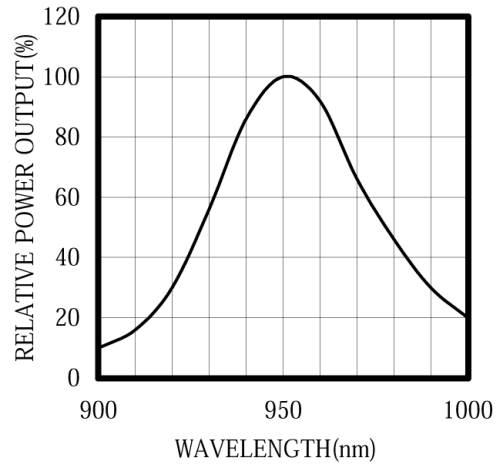
## Electrical & Optical Characteristics (Ta = 25°C)

| ITEMS                            | SYMBOL          | CONDITIONS               | MIN | TYP | MAX | UNIT |
|----------------------------------|-----------------|--------------------------|-----|-----|-----|------|
| Forward Voltage                  | VF              | IF=20mA                  | --  | 1.2 | 1.5 | V    |
| Reverse Current                  | IR              | VR=5V                    | --  | --  | 10  | μA   |
| Peak Emission Wavelength         | λp              | IF=20mA                  | --  | 950 | --  | nm   |
| Spectral Line Half Width         | Δλ              | IF=20mA                  | --  | 50  | --  | nm   |
| Dark Current (I <sub>ceo</sub> ) | ID              | VR=10V                   | --  | --  | 10  | nA   |
| Output Current                   | I <sub>o</sub>  | IF=20mA, VR=10V, d=1mm * | 0.5 | 0.9 | --  | μA   |
| Cross-talk Current               | I <sub>x</sub>  | IF=20mA, VR=10V          | --  | --  | 1.0 | nA   |
| Rise Time (10 to 90%)            | Tr              | VR=10V, IF=20mA, RL=1KΩ  | --  | 2.0 | --  | μS   |
| Fall Time (10 to 90%)            | Tf              | VR=10V, IF=20mA, RL=1KΩ  | --  | 2.0 | --  | μS   |
| Lead Soldering Temperature*2     | T <sub>ls</sub> | --                       | --  | --  | 260 | °C   |

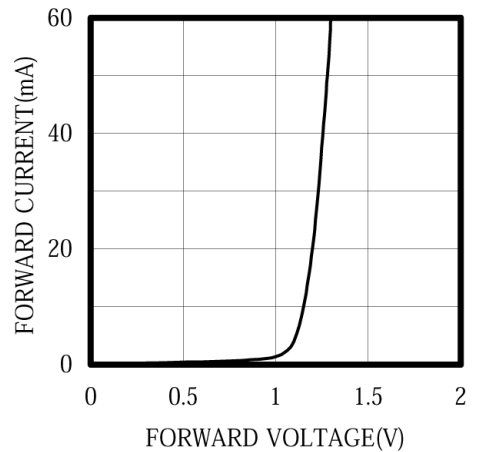
\*1: Measured by reflecting with Aluminum evaporated mirror (d=1.00mm). \*2: Time 5 Sec max, Position: Up to 3mm from the body.



SPECTRAL OUTPUT

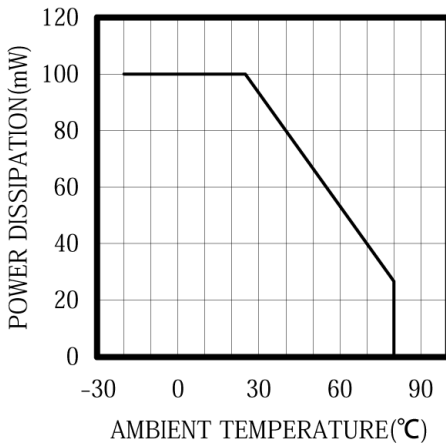


FORWARD I-V CHARACTERISTICS

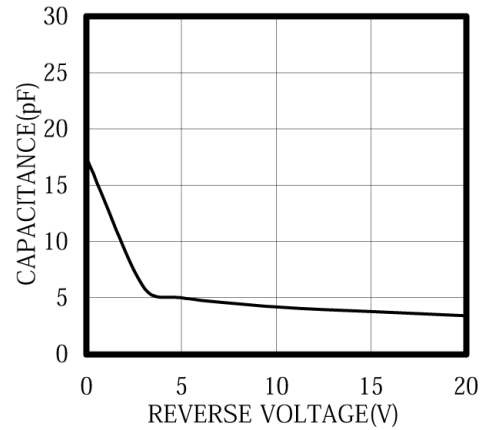


Unit: mm, Tolerance: ±0.2

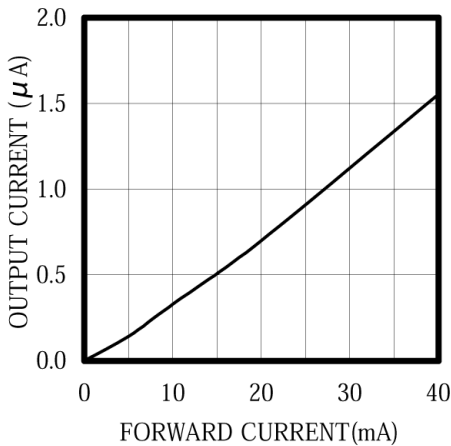
THERMAL DERATING CURVE



CAPACITANCE vs REVERSE VOLTAGE



IF VS I<sub>o</sub> @VR=10V



I<sub>o</sub> VS DISTANCE

